

VS-42CTQ030SPbF

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High Performance Schottky Rectifier, 2 x 20 A

TO-263AB (D²PAK) TO-262AA Base Base common common cathode cathode **Q2** Common 0 3 Anode cathode Anode Anode cathode Anode

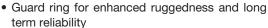
PRODUCT SUMMARY					
I _{F(AV)}	2 x 20 A				
V_{R}	30 V				
V _F at I _F	0.38 V				
I _{RM} max.	183 mA at 125 °C				
T_J max.	150 °C				
E _{AS}	13				
Package	TO-263AB (D ² PAK), TO-262AA				
Diode variation	Common cathode				

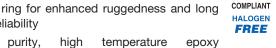
VS-42CTQ030-1PbF

FEATURES

High

- 150 °C T_J operation
- · Center tap configuration
- · Very low forward voltage drop
- High frequency operation





moisture resistance • Meets MSL level 1, per J-STD-020, LF maximum peak

encapsulation for enhanced mechanical strength and

AEC-Q101 qualified

of 260 °C

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		30	V			
I _{FSM}	t _p = 5 μs sine	1100	A			
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.38	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-42CTQ030SPbF VS-42CTQ030-1PbF	UNITS			
Maximum DC reverse voltage	V_{R}	30	V			
Maximum working peak reverse voltage	V_{RWM}	30	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	PARAMETER		TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward per leg current, see fig. 5 per device		1	50 % duty avalo at T- = 121 °C	rootangular wayoform	20		
		I _{F(AV)}	50 % duty cycle at T_C = 121 °C, rectangular waveform		40		
Maximum peak one cycle non	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	1100	A	
surge current per leg, see fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	360		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.90 mH		13	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		3	А	



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ELECTRICAL SPECIFICATION	ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		20 A	T _{.I} = 25 °C	0.48	V		
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	1]=25 0	0.57			
	V FM (1)	20 A	T _{.1} = 125 °C	0.38			
		40 A	1J=125 C	0.51			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Pated V	3	mA		
See fig. 2	IRM (1)	T _J = 125 °C	V _R = Rated V _R	183	IIIA		
Threshold Voltage	V _{F(TO)}	T -T movimum		0.22	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		6.76	mΩ		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal rang	2840	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body 8.0			nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000			V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		В	DC operation	2.0		
		- R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Annuavinanta waight				2	g	
Approximate weight				0.07	oz.	
Mounting torque minimum maximum				6 (5)	kgf · cm	
				12 (10)	(lbf · in)	
Marking device			Case style TO-263AB (D ² PAK)	42CTC	030S	
			Case style TO-262AA	42CTQ	030-1	

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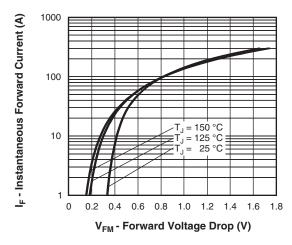


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

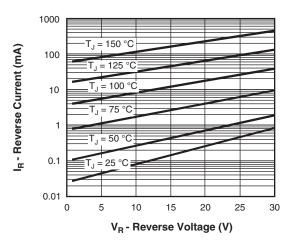


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

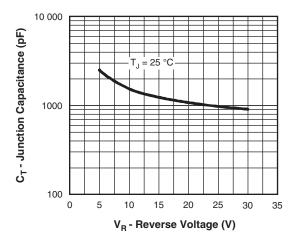


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

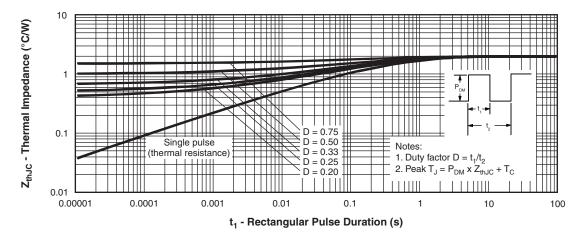


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



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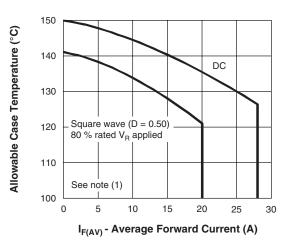


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

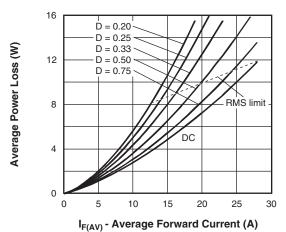


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

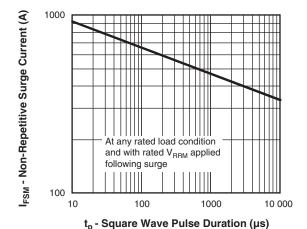


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

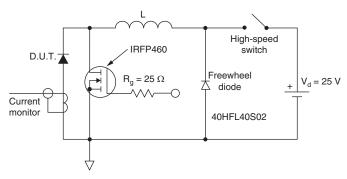


Fig. 8 - Unclamped Inductive Test Circuit

Note

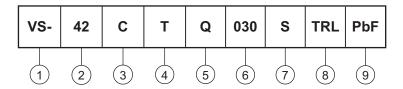
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

VS-42CTQ030SPbF, VS-42CTQ030-1PbF

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (030 = 30 V)

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - PbF = lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-42CTQ030SPBF	50	1000	Antistatic plastic tubes				
VS-42CTQ030STRRPBF	800	800	13" diameter plastic tape and reel				
VS-42CTQ030STRLPBF	800	800	13" diameter plastic tape and reel				
VS-42CTQ030-1PBF	50	1000	Antistatic plastic tubes				

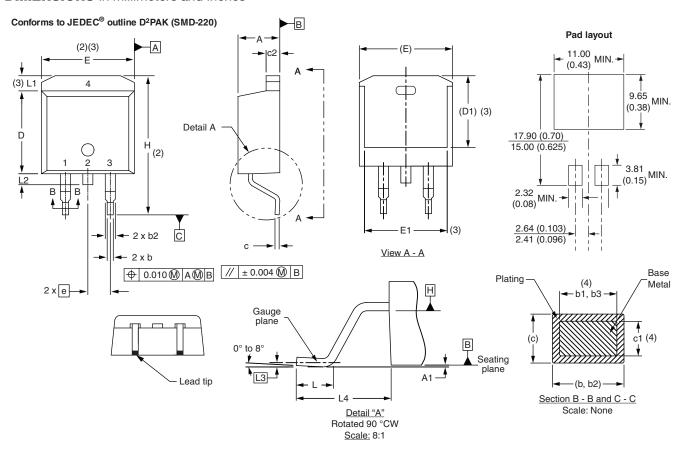
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046		
Differsions	TO-262AA	www.vishay.com/doc?95419		
Part marking information		www.vishay.com/doc?95008		
Packaging information		www.vishay.com/doc?95032		



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

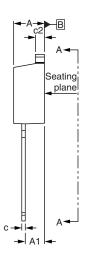
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

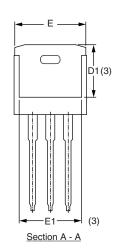


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TO-262

DIMENSIONS in millimeters and inches



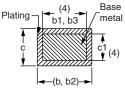


⊕ 0.010 **M** A **M** B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CVMPOL	MILLIN	METERS	INCH	IES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

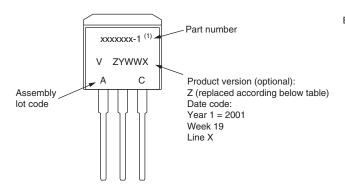
- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



Part Marking Information

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TO-262



Example: This is a xxxxxxx-1 ⁽¹⁾ with assembly lot code AC, assembled on WW 19, 2001

assembled on WW 19, 2001 in the assembly line "X"

Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

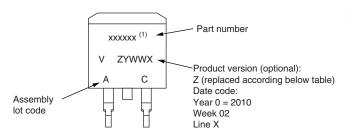
ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
А	Termination lead (Pb)-free		
В	Totally lead (Pb)-free		
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
M	Halogen-free, RoHS-compliant and termination lead (Pb)-free		
N	Halogen-free, RoHS-compliant and totally lead (Pb)-free		
G Green			



Part Marking Information

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D²PAK



Example: This is a xxxxxx ⁽¹⁾ with assembly lot code AC, assembled on WW 02, 2010

Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
А	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
M	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green



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